

View Online at <https://aerobasegroup.com/nsn/5962-01-464-3420>

Maximum Power Dissipation Rating:

1.5 watts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

End Application:

F-15e acft; f-18 acft

Features Provided:

Monolithic and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, memory, digital, cmos ee programmable array logic, monolithic silicon

Voltage Rating And Type Per Characteristic:

-0.5 volts input and 7.0 volts input

Time Rating Per Characteristic:

25.00 nanoseconds access

Memory Device Type:

Pal

Special Features:

Recommended operating supply voltage (vcc) 4.5 to 5.5 vdc; case outline descriptive designator mil-std-1835, gdip3-t24 or cdip4-t24

Supplementary Features:

22-input, 10-output, ee cmos, architecturally generic, programmable and-or array

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A458a0